

Fusion Research Facilities at Sandia National Laboratories

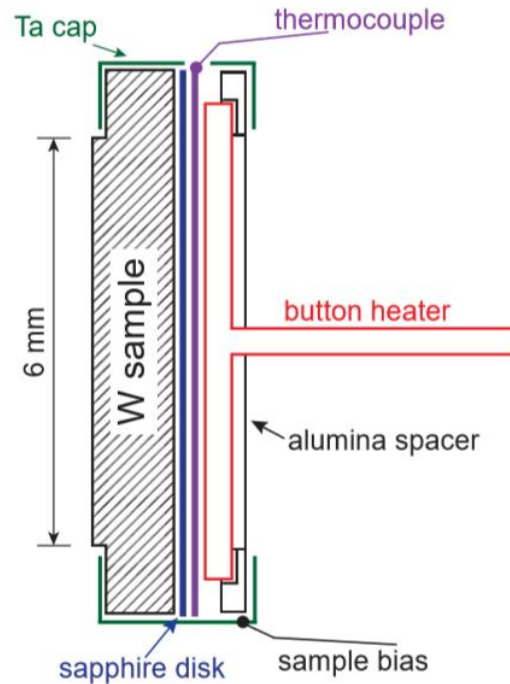
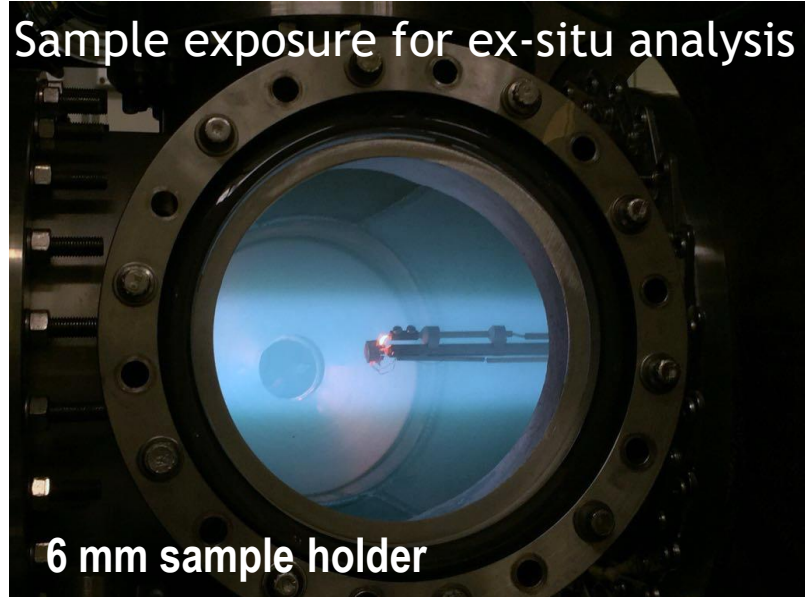
PRESENTED BY

Robert D. Kolasinski

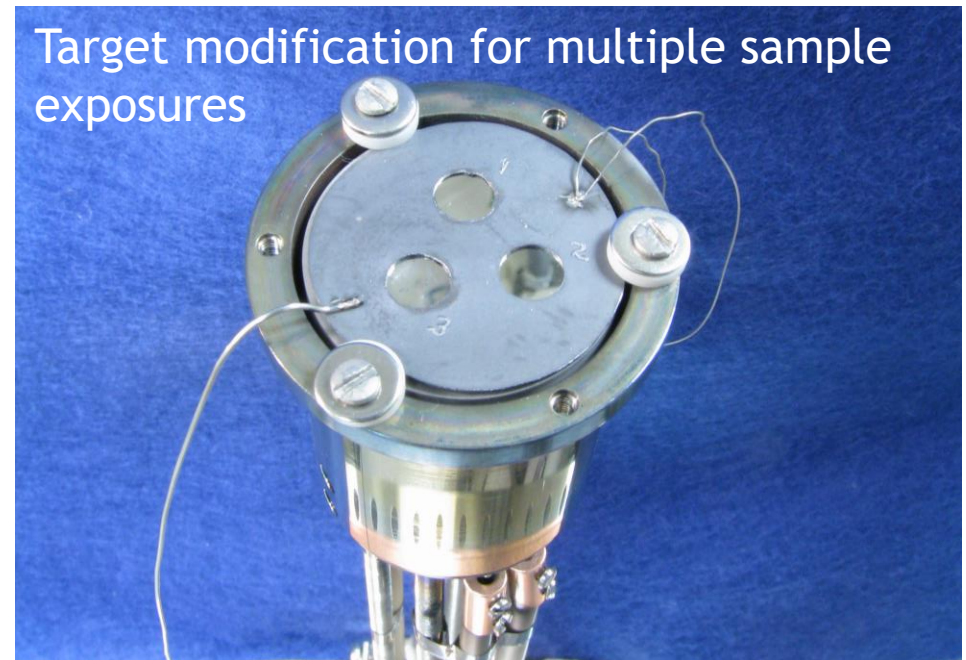
Sandia National Laboratories-Livermore, Energy Innovation Dept.



RF source enables exposure of specimens to He^+ and D_2^+ plasmas



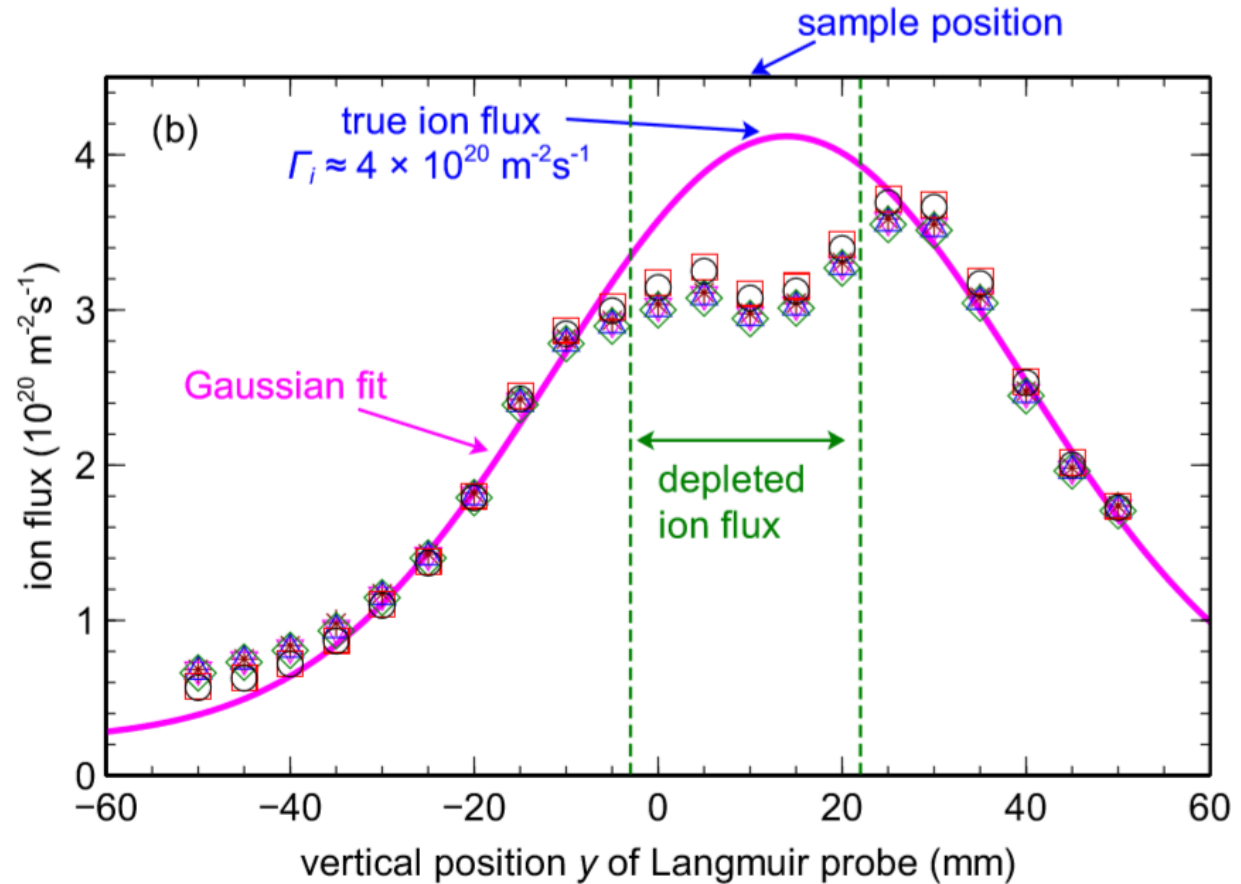
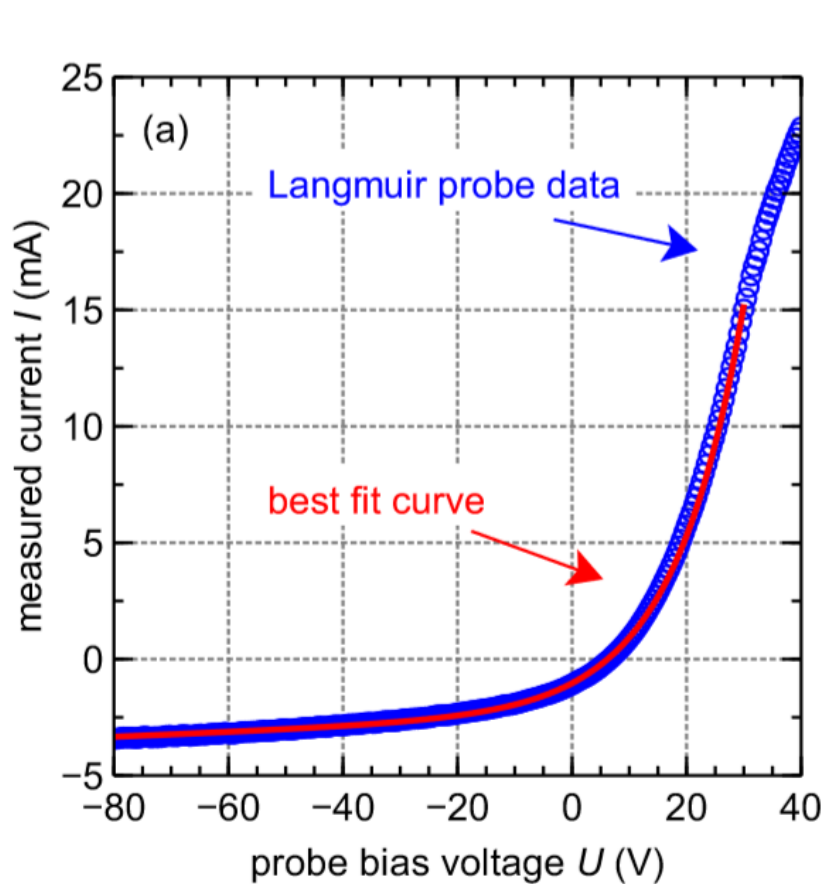
Target modification for multiple sample exposures



RF linear plasma device:

- Axial magnetic field: 185 G
- Lisitano coil with helical cuts machined into each end, based on “short wave” design in Ref. [1].
- Input RF power ~250 W, RF frequency 420 Mz (non-resonant absorption)

Typical exposure conditions for He⁺ plasmas



C. -S. Wong, R. Kolasinski, and J. A. Whaley, (in preparation)

Exposure conditions:

n_{pl}
 T_e

$7 \times 10^{10} \text{ cm}^{-3}$
 11.5 eV

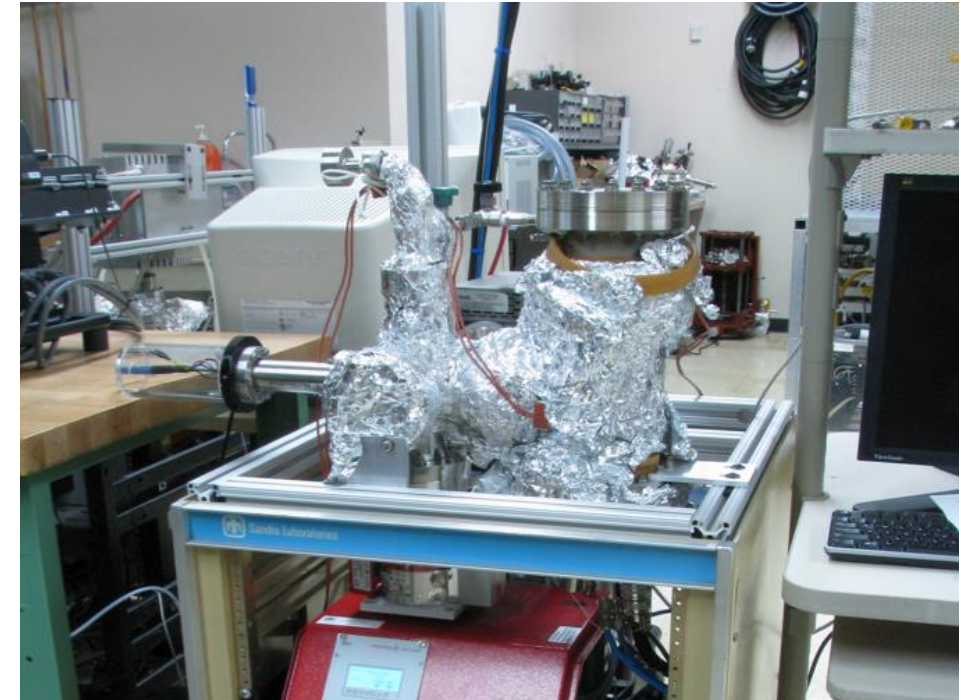
E_{ion}
 Γ_{ion}
 F_{ion}

92 eV
 $1.5 \times 10^{21} \text{ m}^{-2} \text{ s}^{-1}$
 $2.7 \times 10^{25} \text{ m}^{-2}$

High temperature thermal desorption system enables annealing of small samples up to 1600 °C



- High temperature thermal desorption spectrometry
 - Veeco effusion cell heats specimens up to 1600 °C at 17.5 °C/min
 - Released He / D measured using SRS mass spectrometer
 - Lower temperature quartz furnaces (annealing up to 1000 °C also available.)
 - Upgrade to high resolution mass spectrometer planned

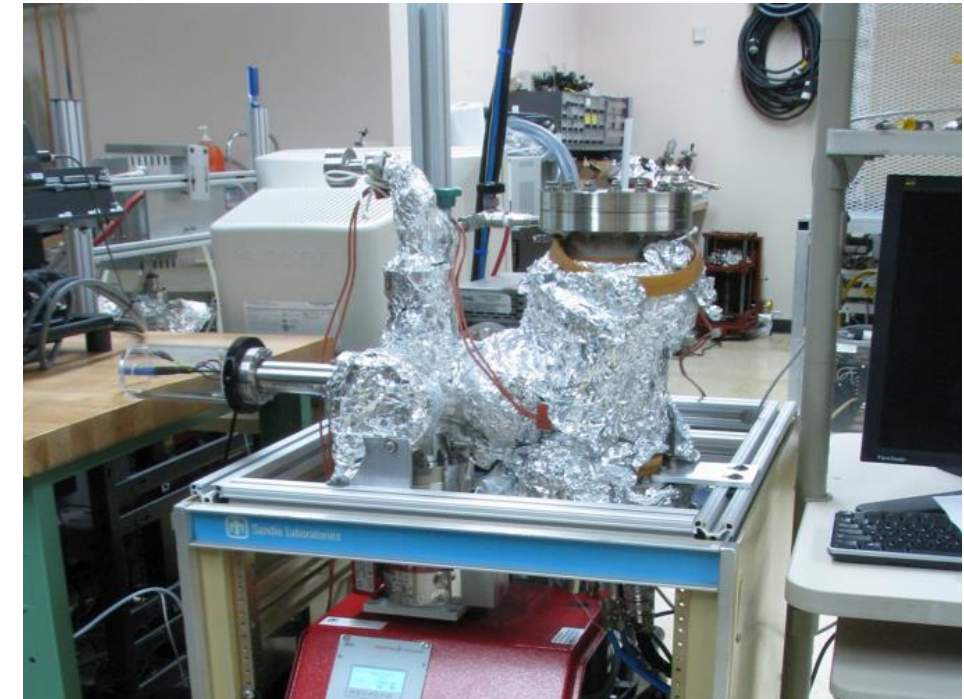
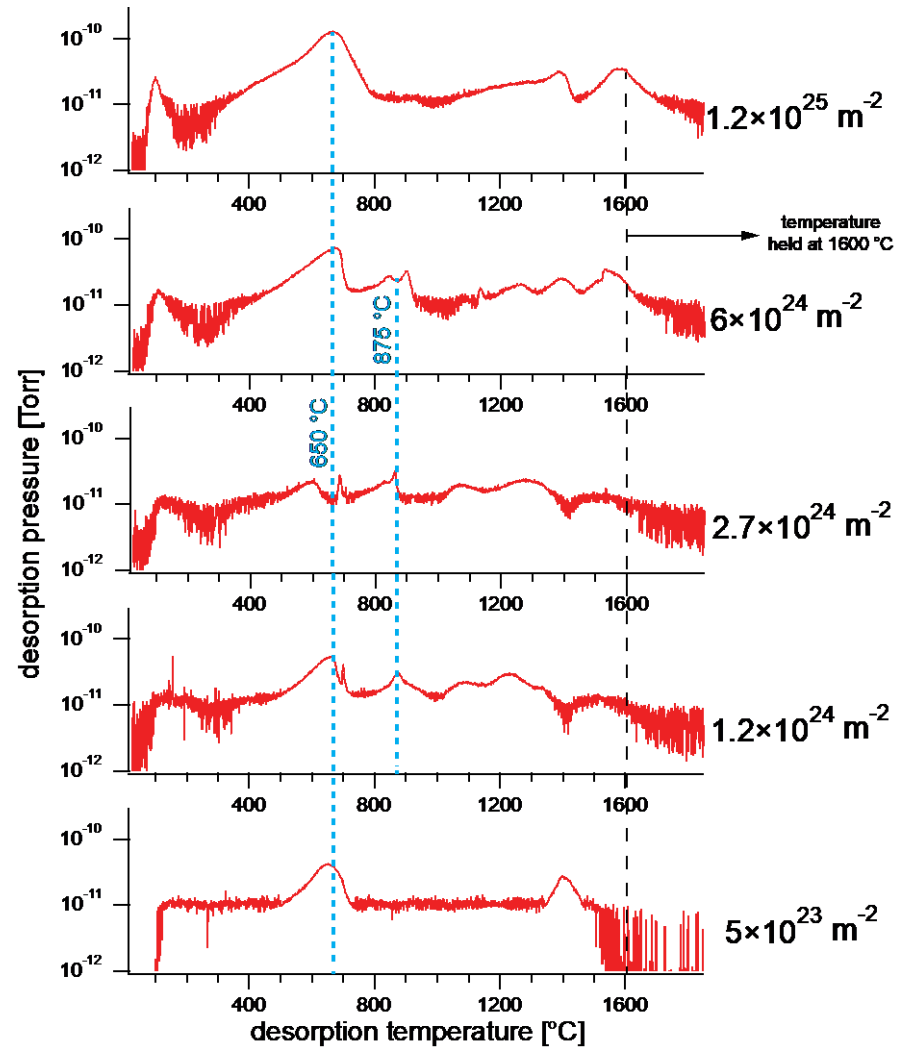


High temperature thermal desorption system

High temperature thermal desorption system enables annealing of small samples up to 1600 °C



He release spectra from plasma exposed W at different fluences



High temperature thermal desorption system

Gas driven permeation instrumentation available for H permeation/diffusion studies

■ Deuterium gas-driven permeation systems presently available:

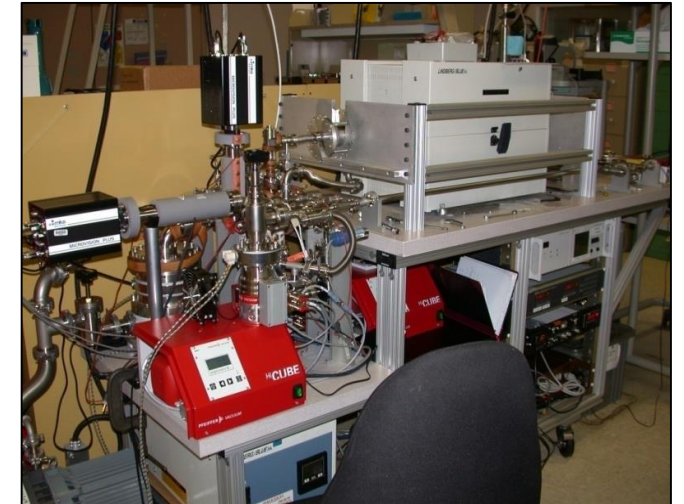
- 1st generation ($150 < T < 500$ °C) used stainless steel construction (VCR seals), evacuated quartz outer tube to reduce D_2 bypass, and low flow to prevent surface contamination

Materials studied: stainless steels, steel alloys, welds, aluminum alloys, nickel, tungsten

- 2nd generation ($50 < T < 1150$ °C) uses Al_2O_3 construction and soft, pressure loaded seals for brittle specimens

Materials studied: stainless steels, SiC, tungsten

$P_{SiC} < 10^{-12}$ mol H_2 m^{-1} s^{-1} $MPa^{-0.5}$

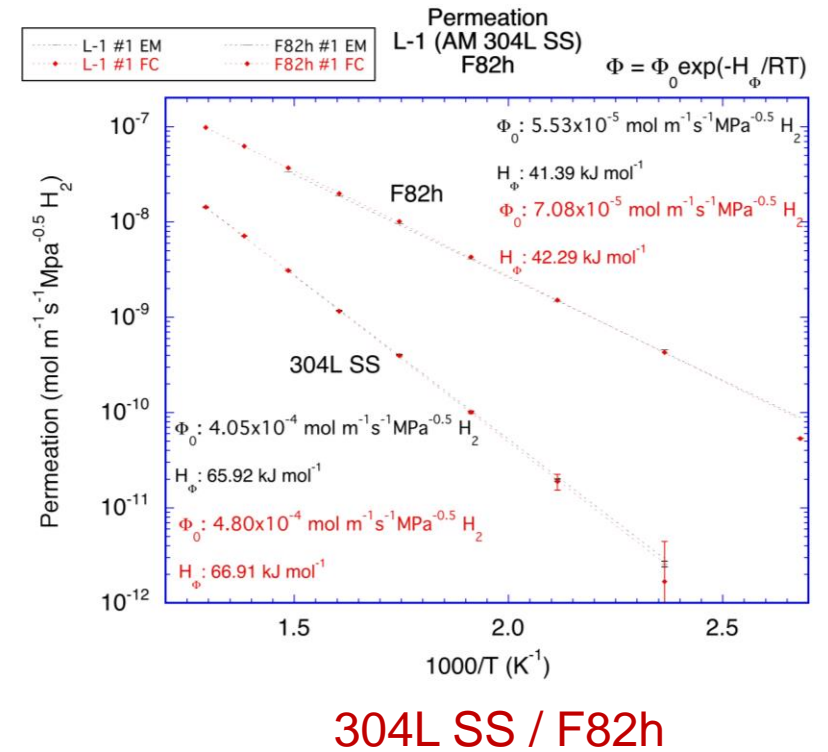
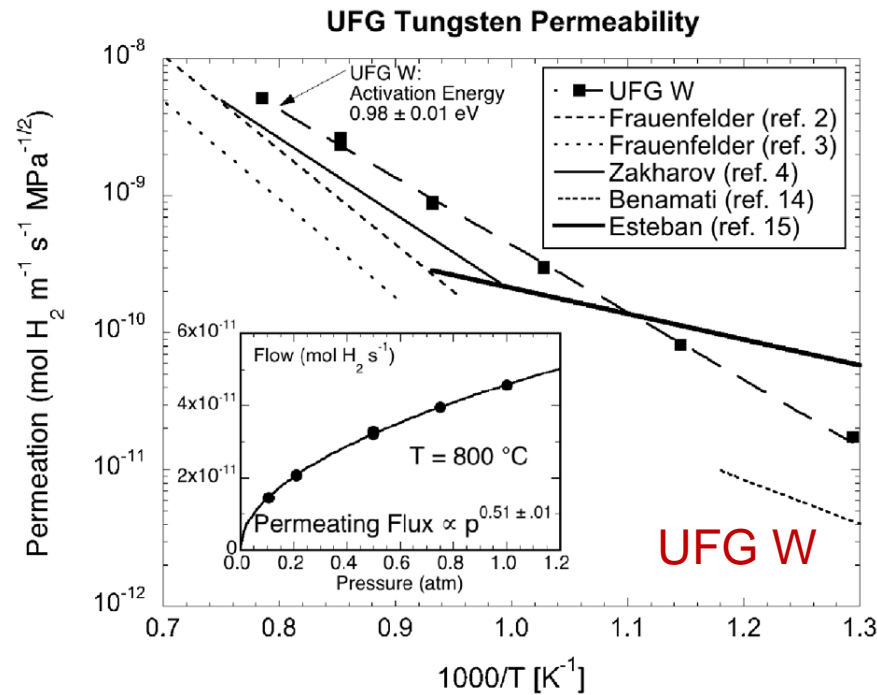
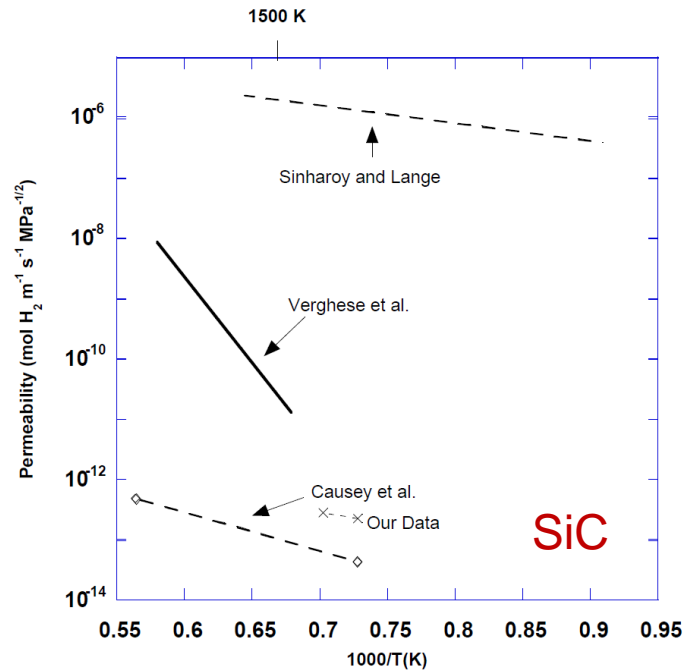


2nd Generation System D_2 permeation system at SNL/CA

Gas driven permeation instrumentation available for H permeation/diffusion studies



Prior work focuses on SiC, W materials, and steels:



Surface analysis capabilities



Low energy ion scattering / direct recoil spectrometry

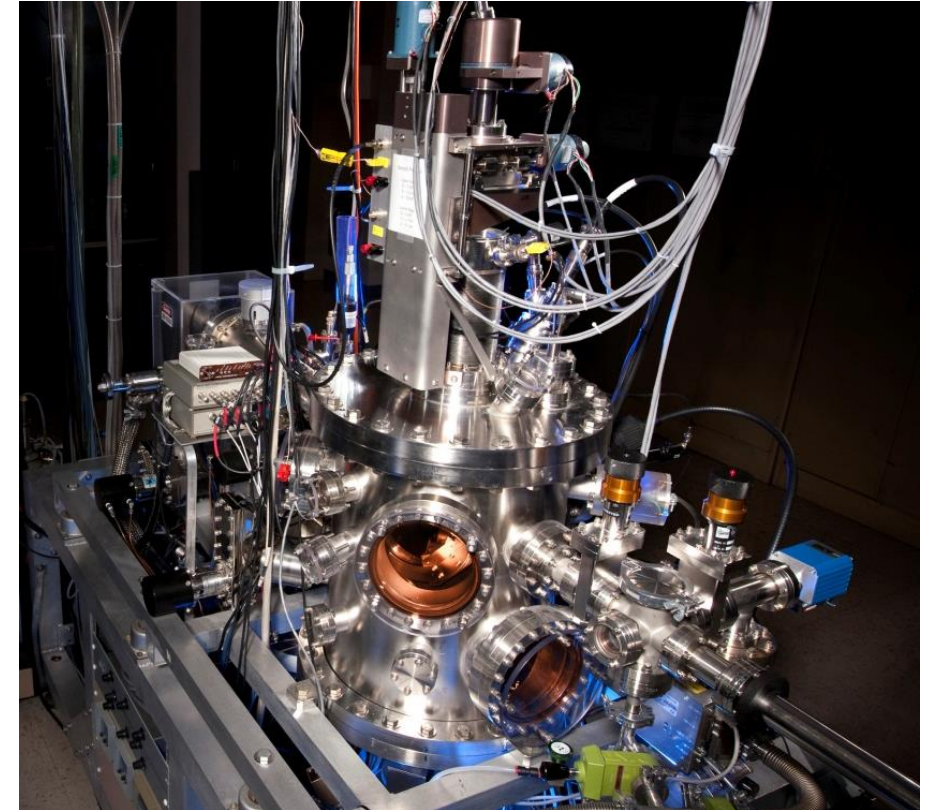
- Provides composition & atomic structure
- Sensitive to chemisorbed H
- Outer-most atomic layer sensitivity

Auger electron spectroscopy

- Precise chemical composition analysis
- Sensitivity to first 5 nm of surface
- Depth profiling, scanning instrument also available

Fourier Transform Infrared Spectrometry

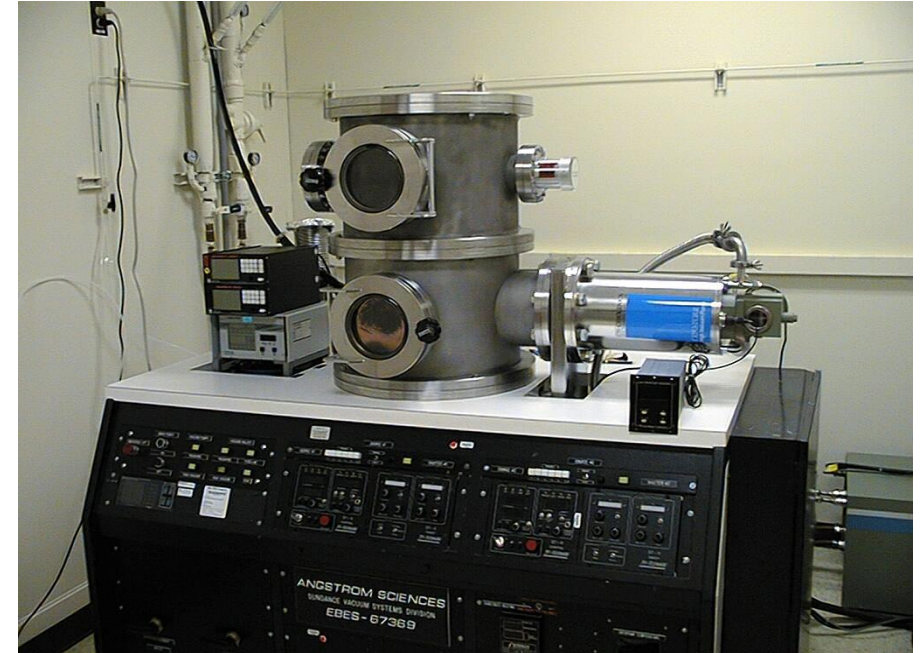
- Vibrational spectroscopy (provides insight into structure & composition)
- Operates at higher pressure (mTorr)



Angle-resolved ion energy spectrometer at Sandia/CA

■ Coating techniques

- Dual electron beam evaporator (low vapor pressure materials, e.g., Pd, Ag, Au, Al, Pt)
- Magnetron sputter deposition (non-magnetic materials), sample pre-sputtering possible
- Typical film thickness achievable: 50 nm – 1 μm



Dual e-beam evaporator

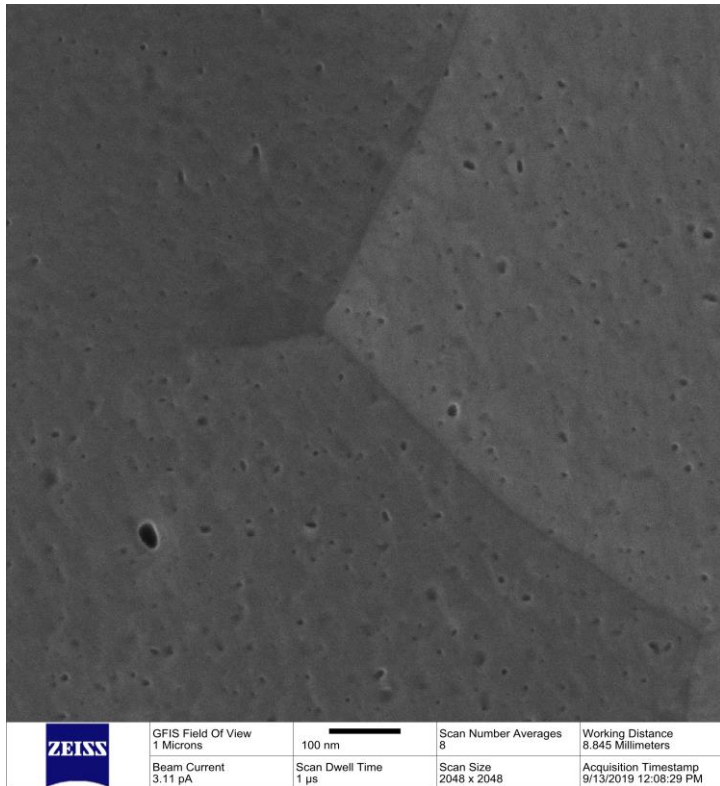


Image of W surface following exposure to He plasma at 700 °C

Capabilities available at Sandia-Livermore:

- SEM/FIB, TEM, EBSD, Scanning Auger

Available through U.C. Berkeley user facility:

- Helium ion microscope / FIB (Zeiss Nano Fab.)

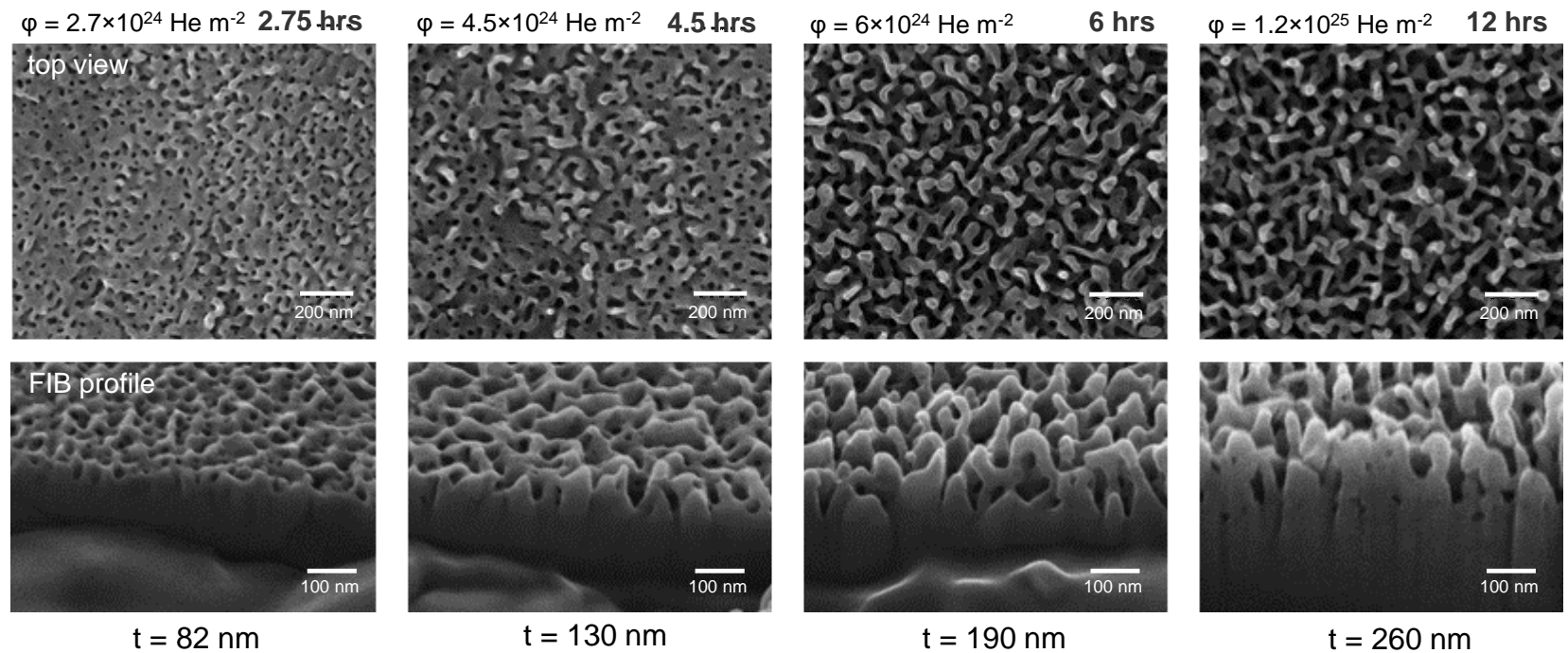


Image sequence (W nanostructure growth)

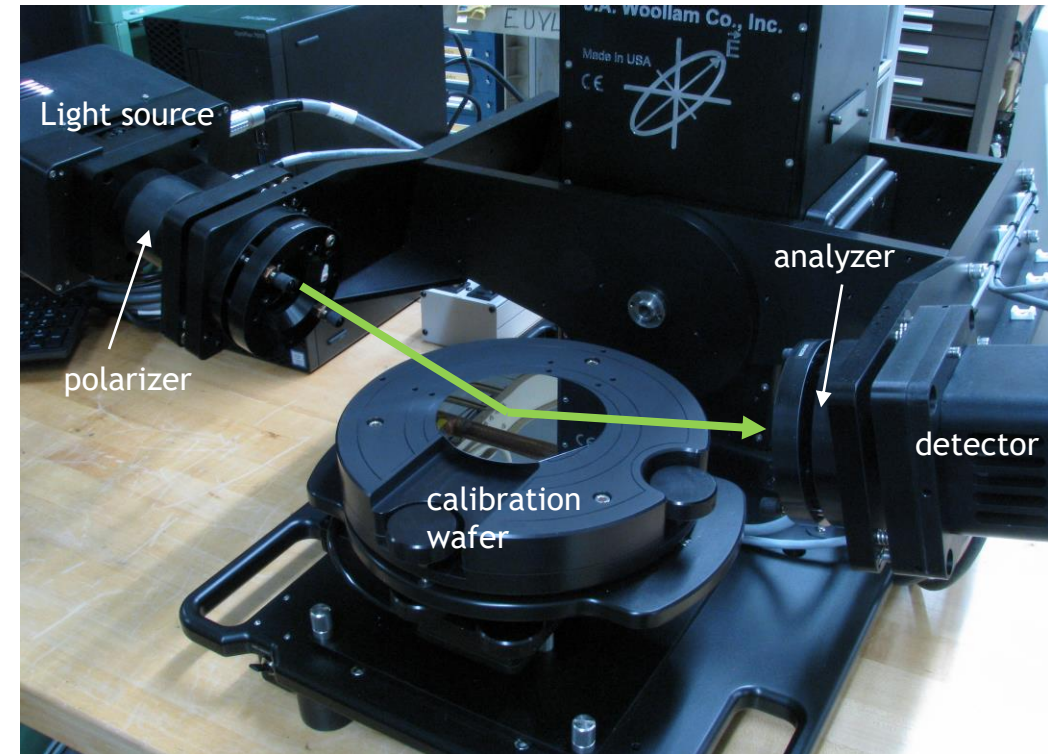
Spectroscopic ellipsometry provides the capability to probe nm-scale changes in the surface

Technique overview:

- Polarized light reflects from a surface
- Polarization change upon reflection (either a phase shift and/or attenuation of s and p waves)
- Changes are strongly sensitive to surface morphology at a nm scale.
- The reflected beam is analyzed using a photodetector / polarizer combination

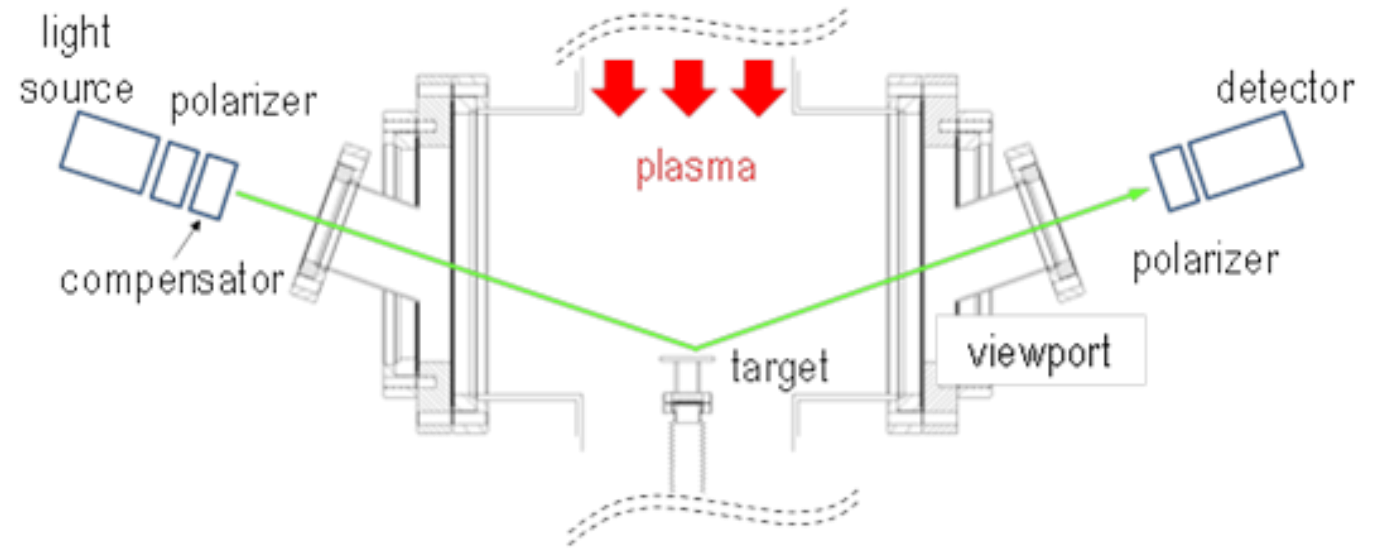
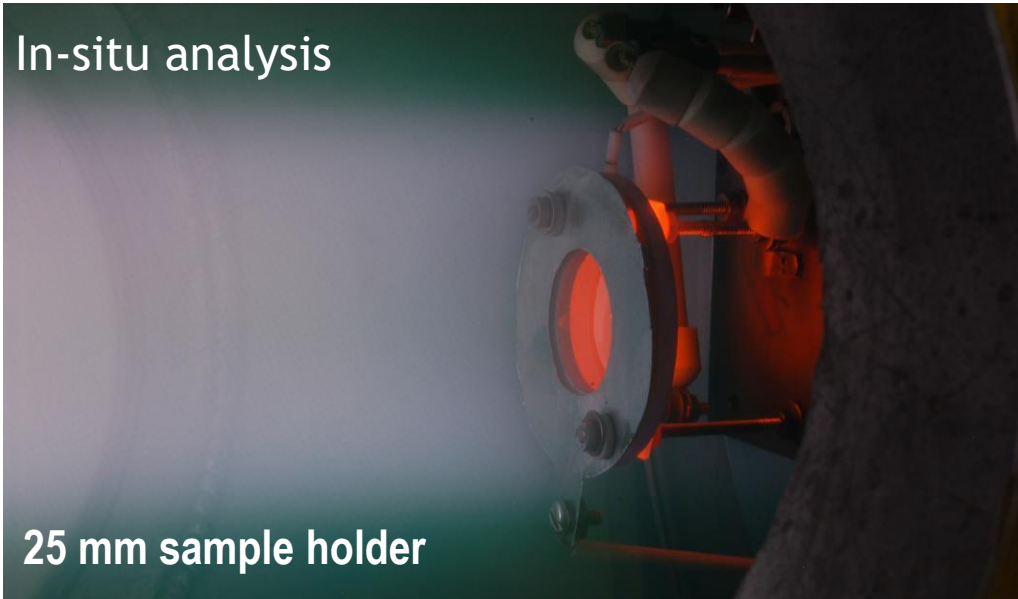
Information provided:

- Frequent use in semiconductor industry for film/oxide thickness
- Optical properties must be calibrated against physical structure



Spectroscopic ellipsometer mounted on variable-angle ex-situ base.

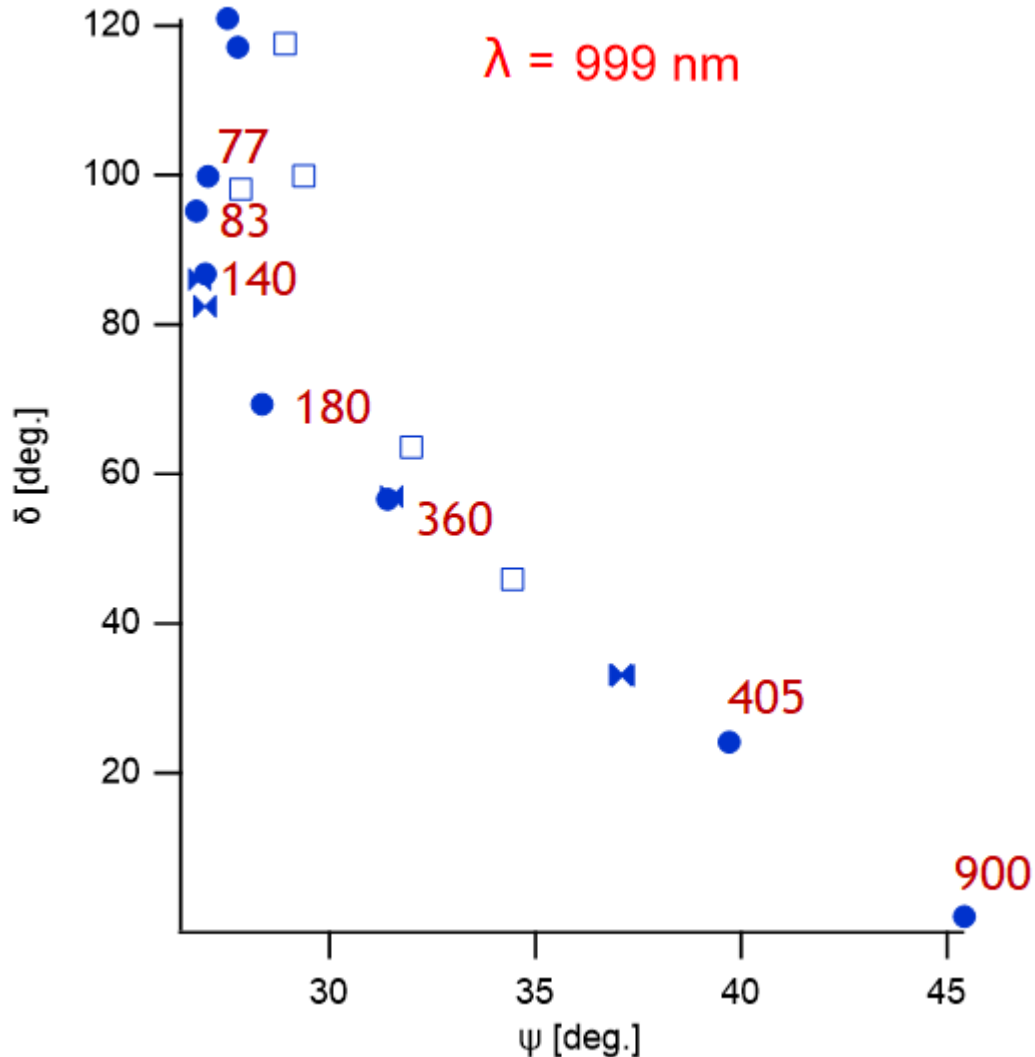
Experimental approach: RF source to expose samples to He plasmas



In-situ ellipsometer configuration

- Spectroscopic ellipsometer range: (245 - 1000 nm)
- Gimbals for alignment (70° relative to normal.)
- Calibrated in place using SiO_2 standards
- Strain-free viewports minimize birefringence
- Sample holder mounted to micrometer positioner to account for thermal expansion

Compiling ellipsometry data reveals a distinct trend in (ψ, δ) coordinates



Several data sets were compiled here for analysis (performed at a range of fluences / temperatures):

- Temperature series
- Fluence series
- Other samples from our collaborators

Notes:

- The data collapse onto a single curve.
- Layer thickness (estimated from HIM) indicated in nm
- Sensitivity is highest during initial stages of exposure

Facilities Summary



INFUSE collaborators are welcome for visits at Sandia:

- Areas of specialization:
 - Hydrogen transport / trapping in plasma-facing materials
 - Gas-driven permeation
 - Surface characterization and microscopy
 - Thermal desorption spectroscopy
 - Thin film deposition
 - Ion implantation, low-flux plasma exposure

General considerations:

- Visitor requests at the NNSA laboratories can take longer than at DOE Office of Science facilities (up to 60 days for non-U.S. citizen.)